

# PC713VxNSZXF Series

# DIP 6 pin Includes Base Terminal Connection Photocoupler



## ■ Description

**PC713VxNSZXF Series** contains an IRED optically coupled to a phototransistor.

It is packaged in a 6 pin DIP, available in SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

Collector-emitter voltage is 80V and CTR is 50% to 600% at input current of 5mA.

#### **■** Features

- 1. 6 pin DIP package
- Double transfer mold package (Ideal for Flow Soldering)
- 3. With base terminal
- 4. High collector-emitter voltage (V<sub>CEO</sub>:80V)
- 5. High isolation voltage between input and output (V<sub>iso(rms)</sub>: 5.0kV)
- 6. Lead-free and RoHS directive compliant

## ■ Agency approvals/Compliance

- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC713V)
- 2. Approved by VDE, DIN EN60747-5-2<sup>(\*)</sup> (as an option), file No. 40008189 (as model No. **PC713V**)
- 3. Package resin: UL flammability grade (94V-0)

## ■ Applications

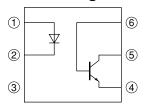
- 1. Home appliances
- 2. Programmable controllers
- 3. Personal computer peripherals

<sup>(\*)</sup> DIN EN60747-5-2: successor standard of DIN VDE0884

 $\theta$  : 0 to 13°



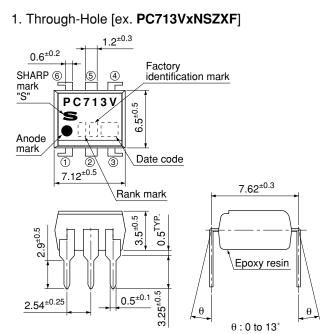
## ■ Internal Connection Diagram



- 1 Anode
- ② Cathode
- ③ NC
- 4 Emitter
- ⑤ Collector
- 6 Base

#### **■** Outline Dimensions

(Unit: mm)



Factory identification mark PC713X Anode mark 2 Date code 1 3  $7.12^{\pm0.3}$  $7.62^{\pm0.3}$ Rank mark 3.5=0.5 0.5 Epoxy resin  $0.5^{\pm0.1}$ 2.54<sup>±0.25</sup>

1.2<sup>±0.3</sup>

 $0.6^{\pm0.2}$ 

SHARP @

mark "S"

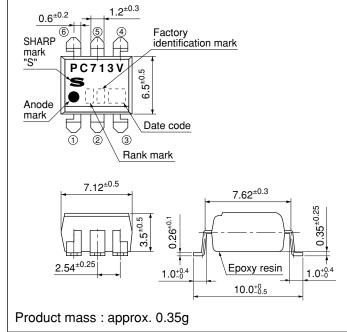
2. Through-Hole (VDE option) [ex. PC713VxYSZXF]

Identification mark

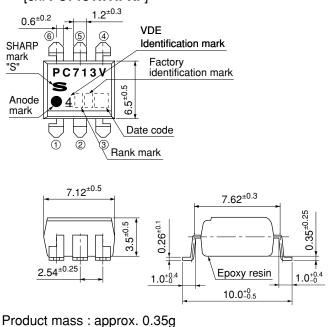
Product mass: approx. 0.36g

Product mass: approx. 0.36g

#### 3. SMT Gullwing Lead-Form [ex. PC713VxNIPXF]



4. SMT Gullwing Lead-Form (VDE option) [ex. PC713VxYIPXF]



Plating material: SnCu (Cu: TYP. 2%)



# Date code (2 digit)

	1st o	digit		2nd digit		
	Year of p	roduction		Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	÷	December	D	

repeats in a 20 year cycle

# Factory identification mark

Factory identification Mark	Country of origin		
no mark	Towns		
	Japan		
	Indonesia		
_	China		

<sup>\*</sup> This factory marking is for identification purpose only.

Please Contact the local SHARP sales reprsentative to see the actual status of the production.

Rank mark
Refer to the Model Line-up



■ Absolute Maximum Ratings

■ Absolute Maximum Ratings $(T_a=25^{\circ}C)$							
Parameter	Symbol	Rating	Unit				
Forward current	$I_F$	50	mA				
*1 Peak forward current	$I_{FM}$	1	A				
Reverse voltage	$V_R$	6	V				
Power dissipation	P	70	mW				
Collector-emitter voltage	$V_{CEO}$	80	V				
Emitter-collector voltage	V <sub>ECO</sub>	6	V				
Collector-base voltage	$V_{CBO}$	80	V				
Emitter-base voltage	$V_{EBO}$	6	V				
Collector current	$I_{C}$	50	mA				
Collector power dissipation	P <sub>C</sub>	150	mW				
Total power dissipation	P <sub>tot</sub>	170	mW				
Operating temperature	Topr	-25 to +100	°C				
torage temperature	$T_{stg}$	-40 to +125	°C				
solation voltage	V <sub>iso (rms)</sub>	5	kV				
Soldering temperature	$T_{sol}$	260	°C				
	Parameter Forward current *1 Peak forward current Reverse voltage Power dissipation Collector-emitter voltage Emitter-collector voltage Collector-base voltage Emitter-base voltage Collector current Collector power dissipation ordal power dissipation Operating temperature torage temperature solation voltage	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				

<sup>\*1</sup> Pulse widths100µs, Duty ratio: 0.001 \*2 40 to 60%RH, AC for 1minute, f=60Hz \*3 For 10s

# **■** Electro-optical Characteristics

 $(T_a=25^{\circ}C)$ 

	•						(1a-25C)	
	Parameter			Conditions	MIN.	TYP.	MAX.	Unit
	Forward voltage		$V_F$	I <sub>F</sub> =20mA	_	1.2	1.4	V
T.,4	Peak forward voltage		$V_{FM}$	I <sub>FM</sub> =0.5A	_	_	3.0	V
Input	Reverse current		$I_R$	$V_R=4V$	_	_	10	μΑ
	Terminal capacitance		Ct	V=0, f=1kHz	_	30	250	pF
	Collector dark current		$I_{CEO}$	$V_{CE}=50V, I_{F}=0$	-	_	100	nA
0	Collector-emitter breakdown voltage		BV <sub>CEO</sub>	$I_{C}=0.1 \text{mA}, I_{F}=0$	80	_	_	V
Output	Emitter-base breakdown voltage		$BV_{EBO}$	$I_{E}=10\mu A, I_{F}=0$	6	_	_	V
	Collector-base breakdown voltage		$BV_{CBO}$	$I_{C}=0.1 \text{mA}, I_{F}=0$	80	_	_	V
	Current transfer ratio		$I_{C}$	$I_F=5mA, V_{CE}=5V$	2.5	_	30	mA
	Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	$I_F=20\text{mA}, I_C=1\text{mA}$	_	0.1	0.2	V
Transfer	Isolation resistance		R <sub>ISO</sub>	DC500V, 40 to 60%RH	5×10 <sup>10</sup>	1×10 <sup>11</sup>	_	Ω
charac- teristics	Floating capacitance		$C_{\mathrm{f}}$	V=0, f=1MHz	_	0.6	1.0	pF
	Cut-off frequency		$f_C$	$V_{CE}=5V$ , $I_{C}=2mA$ , $R_{L}=100\Omega$ $-3dB$	_	80	_	kHz
	Response time	Rise time	t <sub>r</sub>	V 2V I 2m A B 1000	_	4	18	μs
		Fall time	$t_{\rm f}$	$V_{CE}$ =2V, $I_{C}$ =2mA, $R_{L}$ =100 $\Omega$	_	3	18	μs



# ■ Model Line-up

Lead Form	Throu	gh-Hole	SMT Gullwing					I <sub>C</sub> [mA]
Doolsooo		Sle	eve		Taping		Rank mark	$(I_F=5mA,$
Package		50pcs /	'sleeve		1 000pcs / reel			$V_{CE}=5V$ ,
DIN EN60747-5-2		Approved		Approved		Approved		$T_a=25^{\circ}C)$
	PC713V0NSZXF	PC713V0YSZXF	PC713V0NIZXF	PC713V0YIZXF	PC713V0NIPXF	PC713V0YIPXF	with or without	2.5 to 30.0
	PC713V1NSZXF	PC713V1YSZXF	PC713V1NIZXF	PC713V1YIZXF	PC713V1NIPXF	PC713V1YIPXF	A	4.0 to 8.0
	PC713V2NSZXF	PC713V2YSZXF	PC713V2NIZXF	PC713V2YIZXF	PC713V2NIPXF	PC713V2YIPXF	В	6.5 to 13.0
Model No.	PC713V3NSZXF	PC713V3YSZXF	PC713V3NIZXF	PC713V3YIZXF	PC713V3NIPXF	PC713V3YIPXF	С	10.0 to 20.0
	PC713V5NSZXF	PC713V5YSZXF	PC713V5NIZXF	PC713V5YIZXF	PC713V5NIPXF	PC713V5YIPXF	A or B	4.0 to 13.0
	PC713V6NSZXF	PC713V6YSZXF	PC713V6NIZXF	PC713V6YIZXF	PC713V6NIPXF	PC713V6YIPXF	B or C	6.5 to 20.0
	PC713V8NSZXF	PC713V8YSZXF	PC713V8NIZXF	PC713V8YIZXF	PC713V8NIPXF	PC713V8YIPXF	A, B or C	4.0 to 20.0

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Forward Current vs. Ambient Temperature

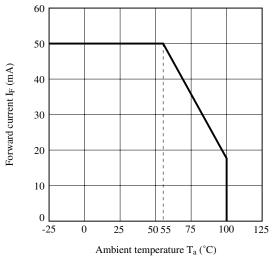


Fig.3 Collector Power Dissipation vs. Ambient Temperature

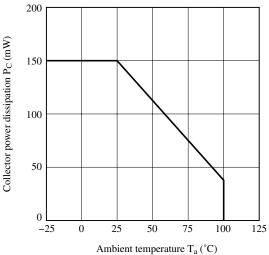


Fig.5 Peak Forward Current vs. Duty Ratio

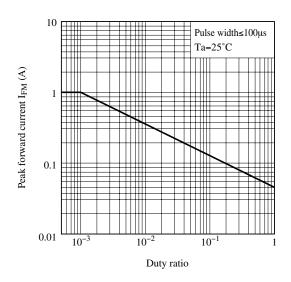


Fig.2 Diode Power Dissipation vs. Ambient Temperature

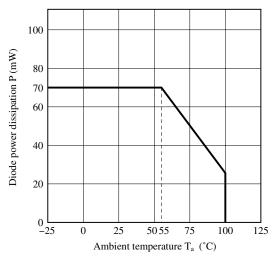


Fig.4 Total Power Dissipation vs. Ambient Temperature

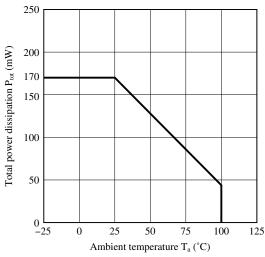


Fig.6 Forward Current vs. Forward Voltage

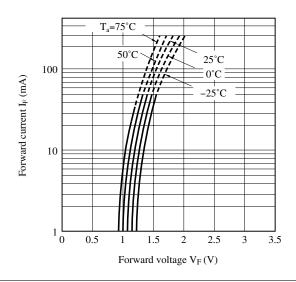




Fig.7 Current Transfer Ratio vs. Forward Current

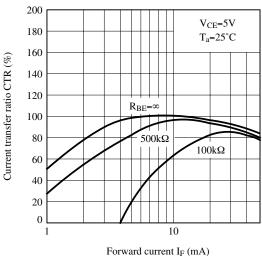


Fig.9 Relative Current Transfer Ratio vs.
Ambient Temperature

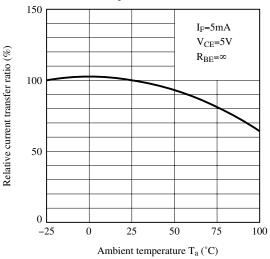


Fig.11 Collector Dark Current vs. Ambient Temperature

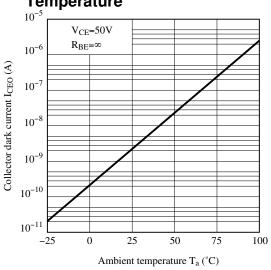


Fig.8 Collector Current vs. Collectoremitter Voltage

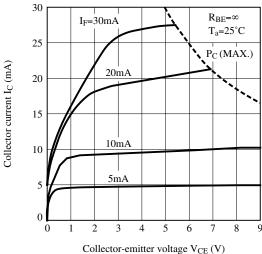


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

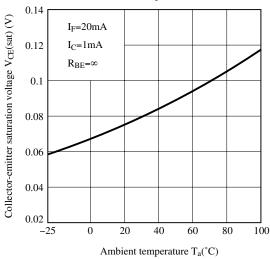


Fig.12 Collector-base Dark Current vs.
Ambient Temperature

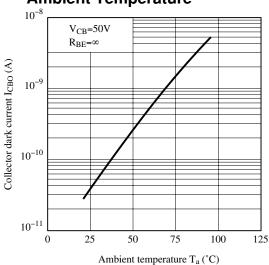




Fig.13 Response Time vs. Load Resistance

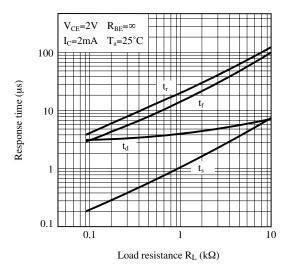


Fig.15 Frequency Response

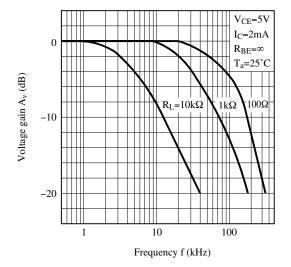
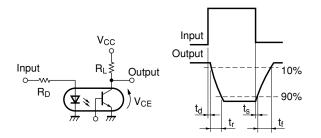
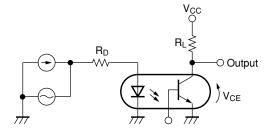


Fig.14 Test Circuit for Response Time



Please refer to the conditions in Fig.13

Fig.16 Test Circuit for Frequency Response



Please refer to the conditions in Fig.15

Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



# ■ Design Considerations

# Design guide

While operating at I<sub>F</sub><1.0mA, CTR variation may increase.

Please make design considering this fact.

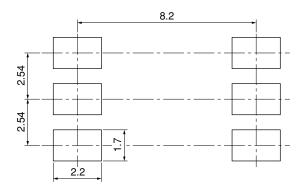
This product is not designed against irradiation and incorporates non-coherent IRED.

# Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

## Recommended Foot Print (reference)



(Unit: mm)

<sup>☆</sup> For additional design assistance, please review our corresponding Optoelectronic Application Notes.



## ■ Manufacturing Guidelines

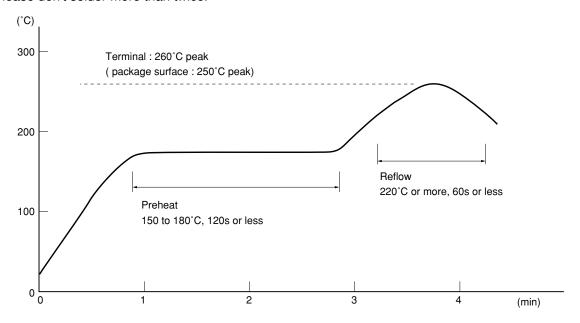
## Soldering Method

#### Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



## Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

#### Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

#### Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



## Cleaning instructions

#### Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

#### Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

#### Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

#### Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



# **■** Package specification

## Sleeve package

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

# Package method

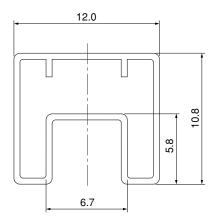
MAX. 50 pcs. of products shall be packaged in a sleeve.

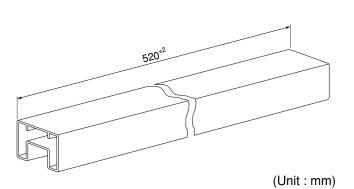
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

#### Sleeve outline dimensions







# ● Tape and Reel package

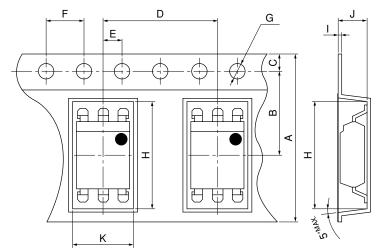
Package materials

Carrier tape: A-PET (with anti-static material)

Cover tape: PET (three layer system)

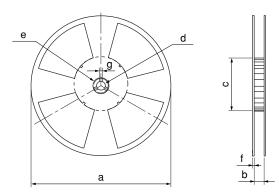
Reel: PS

Carrier tape structure and Dimensions



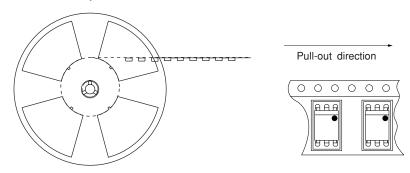
[	Dimensions List					(Unit:mm)	
	A	В	C	D	Е	F	G
	16.0 <sup>±0.3</sup>	7.5 <sup>±0.1</sup>	1.75 <sup>±0.1</sup>	12.0 <sup>±0.1</sup>	2.0 <sup>±0.1</sup>	4.0 <sup>±0.1</sup>	φ1.5 <del>+</del> 8.1
	Н	I	J	K			
-	10.4 <sup>±0.1</sup>	0.4 <sup>±0.05</sup>	4.2 <sup>±0.1</sup>	7.8 <sup>±0.1</sup>			

#### Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)		
a	b	c	d	
330	330 17.5 <sup>±1.5</sup>		13±0.5	
e	e f			
23 <sup>±1.0</sup>	2.0±0.5	2.0±0.5		

# Direction of product insertion



[Packing: 1 000pcs/reel]



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  - --- Personal computers
  - --- Office automation equipment
  - --- Telecommunication equipment [terminal]
  - --- Test and measurement equipment
  - --- Industrial control
  - --- Audio visual equipment
  - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
- (iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:
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  - --- Telecommunication equipment [trunk lines]
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[E218] Sheet No.: D2-A04302EN



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- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001:
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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